

SURFACE MOUNT GLASS PASSIVATED SUPERFAST RECTIFIER**Reverse Voltage 200 to 600V, Forward Current 1.0A****DESCRIPTION:**

The ALPMURS120B through ALPMURS160B is Surface Mount Glass Passivated Superfast Rectifier are Low profile package with Reverse Voltage 200 to 600V, Forward Current 1.0A. It is Ideal for very high frequency switching power supplies.

FEATURES:

- Glass passivated chip junction
- Ultrafast recovery time for high efficiency
- For surface mounted application
- High Temp Soldering: 260°C For 10seconds at Terminals
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- RoHS Compliant
- REACH Compliant

APPLICATIONS:

- Ideally suited for use in very high frequency switching power supplies, inverters and as a free-wheeling diode.

MECHANICAL CHARACTERISTICS

- Terminals: Solder plated, solderable per MIL-STD-750, method 2026.
- Case: JEDEC DO-214AA (SMB) molded plastic body over glass passivated chip.
- Polarity: Indicated by cathode band.

TYPICAL DEVICE CHARACTERISTICS

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ALPMURS120B	ALPMURS140B	ALPMURS160B	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	V
Working peak reverse voltage	V _{RWM}	200	400	600	V
Maximum DC blocking voltage	V _{DC}	200	400	600	V
Maximum average forward rectified current (See Fig.1)	@T _L =150°C	1.0			A
	@T _L =125°C	2.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	40	35		A
Operating junction temperature range	T _J	-55 to +150			°C
Storage temperature range	T _{STG}	-55 to +150			°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	ALPMURS120B	ALPMURS140B	ALPMURS160B	UNIT
Maximum instantaneous forward voltage	I _F = 1.0 A T _J = 25 °C	V _F	0.875	1.25		V
	I _F = 1.0 A T _J = 150 °C		0.71	1.05		
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C	I _R	2.0	5.0		µA
	T _A = 125 °C		50			
Typical reverse recovery time	I _F = 0.5A, I _R = 1.0A, I _{RR} = 0.25A	t _{rr}	25	50		nS
	I _F =1.0A, di/dt=50A/µS, V _R =30V I _{rr} =10% I _{RM}		35	75		
	I _F =1.0A, di/dt=100A/µS, recovery to 1.0V		25	50		



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THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	ALPMURS120B	ALPMURS140B	ALPMURS160B	UNIT
Typical thermal resistance ⁽¹⁾	junction to ambient	R _{θJA}	85			°C/W
	junction to case	R _{θJC}	15			
	junction to lead	R _{θJL}	20			

Note:

⁽¹⁾ The thermal resistance from junction to ambient and from junction to lead mounted on P.C.B with 8.0 x 8.0mm copper pads.

TYPICAL DEVICE CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

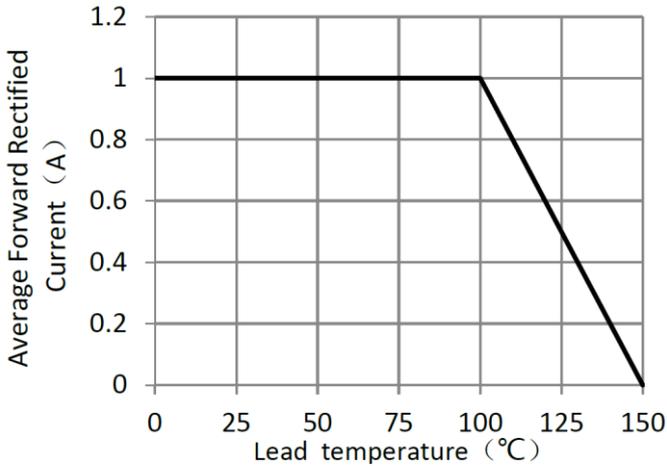


Fig1. Forward Current Derating Curve

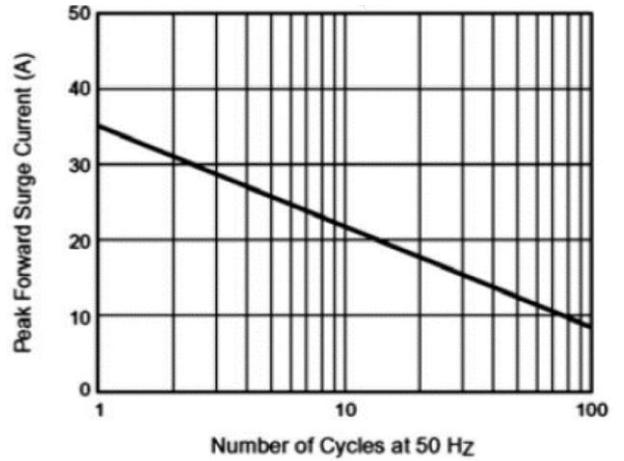


Fig2. Maximum Non-Repetitive Peak Forward Surge Current

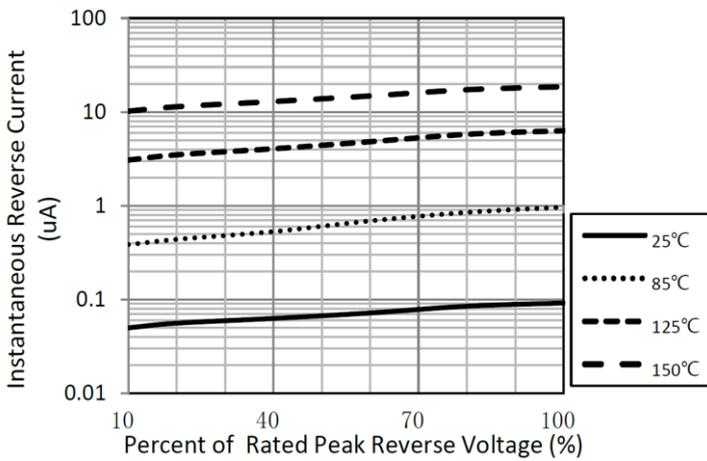


Fig3. Typical Reverse Characteristics

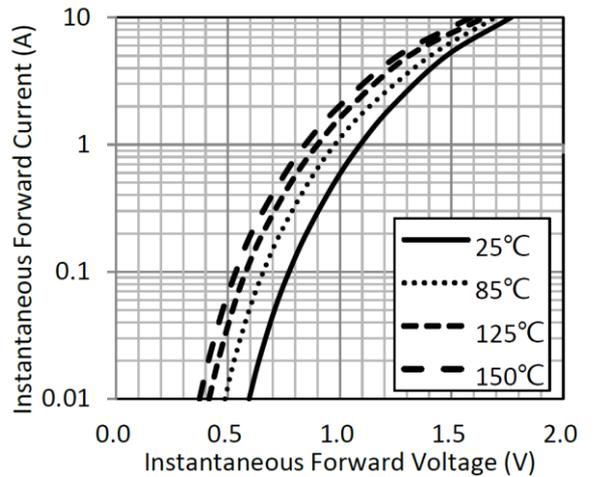


Fig4. Typical Instantaneous Forward Characteristics

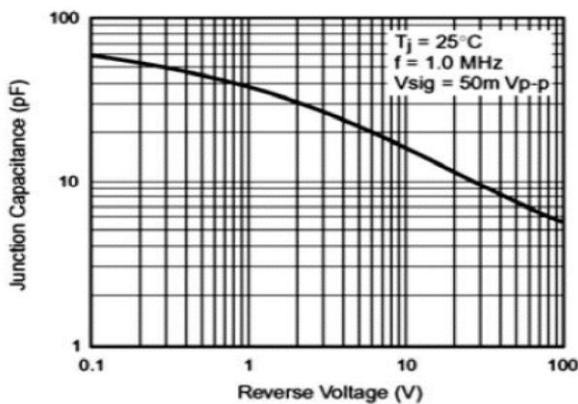
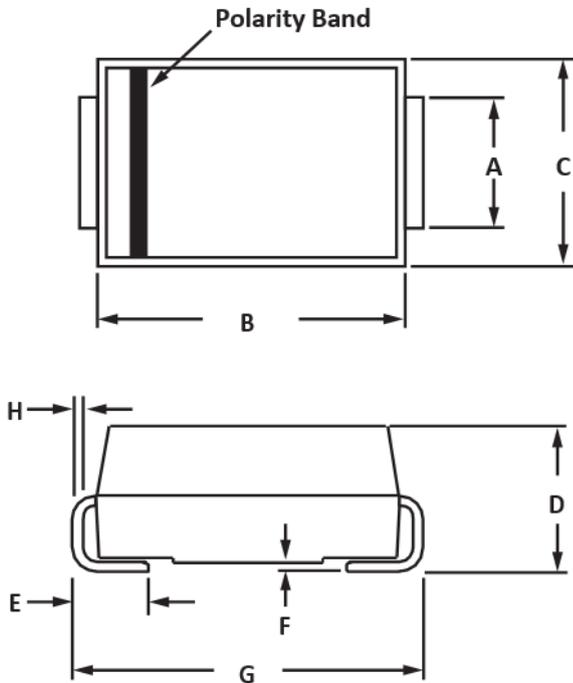


Fig5. Typical Junction Capacitance

PACKAGE INFORMATION

DO-214AA (SMB)

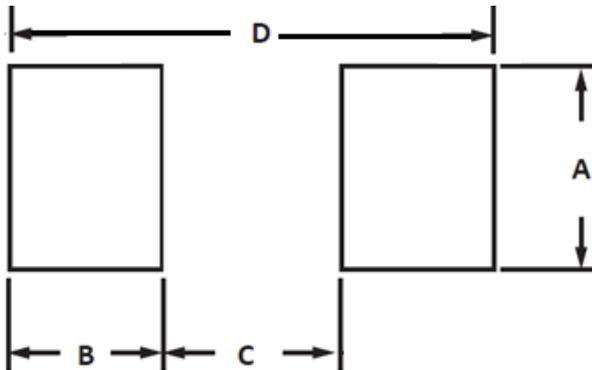


OUTLINE DIMENSIONS

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.93	2.08	0.076	0.082
B	4.25	4.75	0.167	0.187
C	3.48	3.73	0.137	0.147
D	1.99	2.61	0.078	0.103
E	0.90	1.41	0.035	0.056
F	0.05	0.20	0.002	0.008
G	5.26	5.46	0.207	0.215
H	0.15	0.31	0.006	0.012

NOTES

1. Dimensions are exclusive of mold flash and metal burrs.



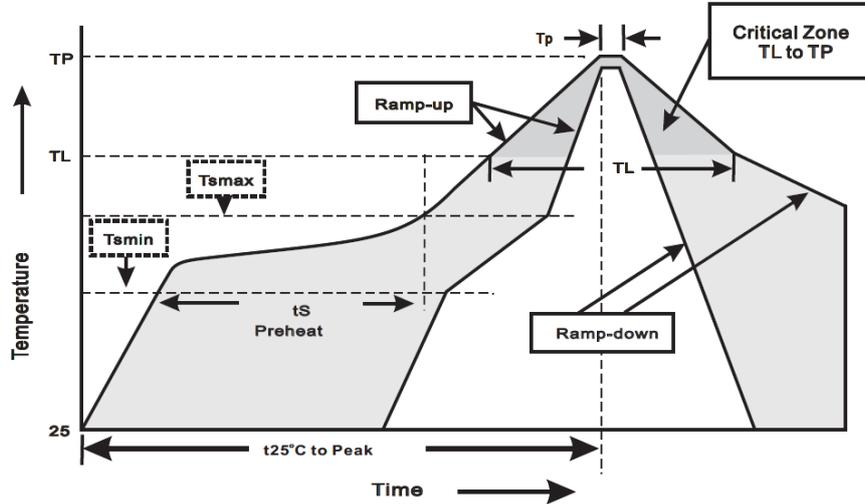
PAD LAYOUT DIMENSIONS

DIM	MILLIMETERS	INCHES
	REF.	REF.
A	2.30	0.091
B	1.60	0.063
C	2.90	0.114
D	6.10	0.24

SOLDERING PARAMETERS

SUGGESTED THERMAL PROFILES FOR SOLDERING PROCESSES

1. Storage environment: Temperature=5 °C~40 °C Humidity=55% ±25%
2. Reflow soldering of surface-mount devices



3. Reflow soldering

PROFILE FEATURE	SOLDERING CONDITION
Average ramp-up rate (TL to TP)	<3 °C/sec
Preheat	
- Temperature Min (T _{smin})	150 °C
- Temperature Max (T _{smax})	200 °C
- Time (min to max) (t _s)	60 ~ 120 sec
T _{smax} to TL	
- Ramp-upRate	<3 °C/sec
Time maintained above:	
- Temperature (TL)	217 °C
- Time(tL)	60 ~ 260 sec
Peak Temperature (TP)	255 °C-0/+5 °C
Time within 5 °C of actual Peak Temperature(tp)	10 ~ 30 sec
Ramp-down Rate	<6 °C/sec
Time 25 °C to Peak Temperature	<6 minutes



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PRODUCT HIGH RELIABILITY TEST CAPABILITIES

ITEM	TEST CONDITIONS	STANDARD
Solder Resistance	At 260±5°C for 10±Sec.	MIL-STD-750D METHOD-2031
Solderability	At 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
High Temperature Reverse Bias	$V_{BR} = V_{BR\ NOM} * 80\%$ at $T_J = 150^\circ$ for 168 hrs.	MIL-STD-750D METHOD-1038
Pressure Cooker	15PSIG at $T_A = 121^\circ\text{C}$ for 4Hrs	JESD22-A102
Temperature Cycling	-55°C to +125°C dwelled for 30min and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
Humidity	At $T_A = 85^\circ\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
High Temperature Storage Life	At 175°C for 1000hrs.	MIL-STD-750D METHOD-1031



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CUSTOMER NOTE:

DISCLAIMER

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2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).



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